

Rectifier Diode

Type D143-800-28

High power cycling capability
 Low on-state and switching losses
 Optimized for line frequency rectifiers
 Designed for traction and industrial applications

Average forward current			I_{FAV}	800 A		
Repetitive peak reverse voltage			V_{RRM}	1800 ÷ 2800 V		
V_{RRM} , V	1800	2000	2200	2400	2600	2800
Voltage code	18	20	22	24	26	28
T_j , °C			-60 ÷ 175			

MAXIMUM ALLOWABLE RATINGS

Symbols and parameters		Units	Values	Test conditions	
ON-STATE					
I_{FAV}	Average forward current	A	800 1235	$T_c=136$ °C; Double side cooled; $T_c=100$ °C; Double side cooled; 180° half-sine wave; 50 Hz	
I_{FRMS}	RMS forward current	A	1256	$T_c=136$ °C; Double side cooled; 180° half-sine wave; 50 Hz	
I_{FSM}	Surge forward current	kA	18.0 20.0	$T_j=T_{j \max}$ $T_j=25$ °C	180° half-sine wave; 50 Hz ($t_p=10$ ms); single pulse; $V_R=0$ V;
			19.0 21.9	$T_j=T_{j \max}$ $T_j=25$ °C	180° half-sine wave; 60 Hz ($t_p=8.3$ ms); single pulse; $V_R=0$ V;
I^2t	Safety factor	$A^2s \cdot 10^3$	1620 2140	$T_j=T_{j \max}$ $T_j=25$ °C	180° half-sine wave; 50 Hz ($t_p=10$ ms); single pulse; $V_R=0$ V;
			1495 1990	$T_j=T_{j \max}$ $T_j=25$ °C	180° half-sine wave; 60 Hz ($t_p=8.3$ ms); single pulse; $V_R=0$ V;
BLOCKING					
V_{RRM}	Repetitive peak reverse voltages	V	1800 ÷ 2800	$T_{j \min} < T_j < T_{j \max}$; 180° half-sine wave; 50 Hz;	
V_{RSM}	Non-repetitive peak reverse voltages	V	1900 ÷ 2900	$T_{j \min} < T_j < T_{j \max}$; 180° half-sine wave; 50 Hz; single pulse;	
V_R	Reverse continuous voltages	V	$0.75 \cdot V_{RRM}$	$T_j=T_{j \max}$;	
THERMAL					
T_{stg}	Storage temperature	°C	-60 ÷ 50		
T_j	Operating junction temperature	°C	-60 ÷ 175		
MECHANICAL					
F	Mounting force	kN	14.0 ÷ 16.0		
a	Acceleration	m/s^2	50 100	Device unclamped Device clamped	

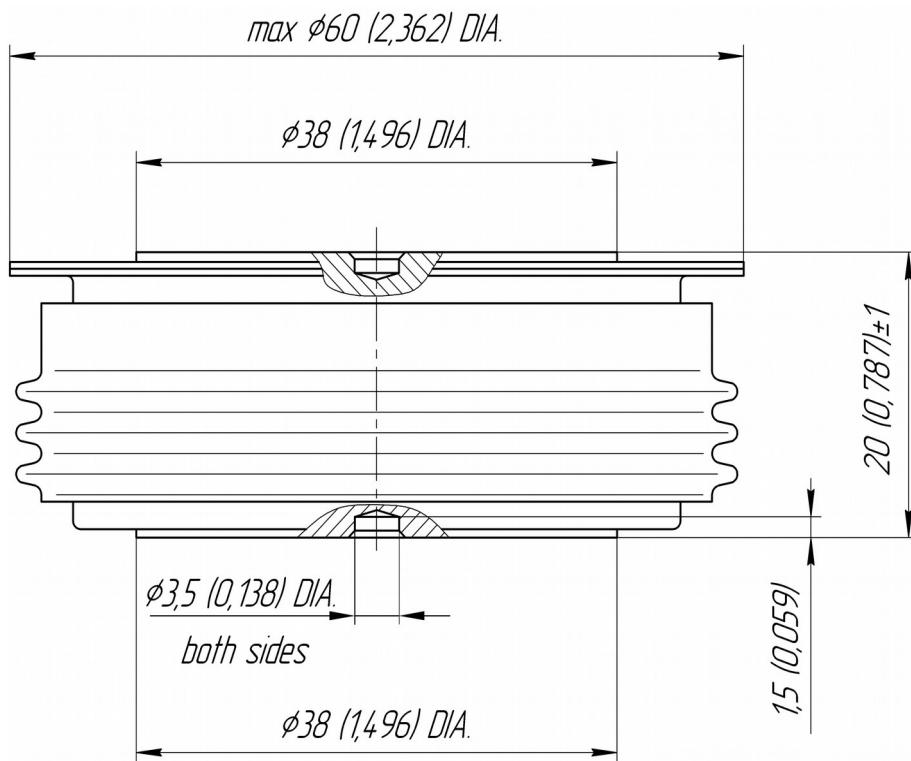
CHARACTERISTICS

Symbols and parameters		Units	Values	Conditions	
ON-STATE					
V _{FM}	Peak forward voltage, max	V	1.55	T _j =25 °C; I _{FM} =2512 A	
V _{F(TO)}	Forward threshold voltage, max	V	1.00	T _j =T _{j max} ; V _R =V _{RRM}	
r _T	Forward slope resistance, max	mΩ	0.410	0.5 π I _{FAV} < I _T < 1.5 π I _{FAV}	
BLOCKING					
I _{RRM}	Repetitive peak reverse current, max	mA	70	T _j =T _{j max} ; V _R =V _{RRM}	
THERMAL					
R _{thjc}	Thermal resistance, junction to case, max	°C/W	0.027	Direct current	Double side cooled
R _{thjc-A}			0.059		Anode side cooled
R _{thjc-K}			0.049		Cathode side cooled
R _{thck}	Thermal resistance, case to heatsink, max	°C/W	0.006	Direct current	
MECHANICAL					
w	Weight, typ	g	260		
D _s	Surface creepage distance	mm (inch)	23.69 (0.933)		
D _a	Air strike distance	mm (inch)	19.10 (0.752)		

PART NUMBERING GUIDE

D	143	800	28	N
1	2	3	4	5

1. D — Rectifier Diode
2. Design version
3. Average forward current, A
4. Voltage code
5. Ambient conditions: N – normal; T – tropical

OVERALL DIMENSIONS**Package type: D.C2**

All dimensions in millimeters (inches)